

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

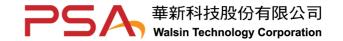
Capacitor Arrays Series (10V to 50V)

4 x 0402, 4 x 0603 Size

NP0, X7R & Y5V Dielectrics

RoHS Compliance

*Contents in this sheet are subject to change without prior notice.



1. INTRODUCTION

WTC middle and high voltage series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords increased capacitance values in a given case size and voltage rating.

WTC capacitor arrays are developed to offer designers the opportunity to lower placement costs increase assembly line output through lower component count per board.

2. FEATURES

- a. High density mounting due to mounting space saving.
- b. Mounting cost saving.
- c. Increased throughput.

3. APPLICATIONS

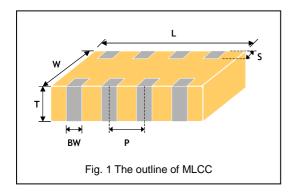
- For use as a bypass for digital and analog signal line noise
- b. Computer motherboards and peripherals.
- c. The other common electronic circuits.

4. HOW TO ORDER

Y	<u>4C</u>	<u>3</u>	<u>B</u>	<u>103</u>	<u>K</u>	<u>500</u>	<u>C</u>	I
<u>Series</u>	Cap. Nr.	Termination pitch	Dielectric	<u>Capacitance</u>	Tolerance	Rated voltage	<u>Termination</u>	<u>Packaging</u>
Y=Capacitor	4C =4xCap	3 =0.03" pitch	N=NP0	Two significant	J =±5%	Two significant	C =Cu/Ni/Sn	T=7" reeled
array		2 =0.02" pitch	(C0G)	digits followed	K =±10%	digits followed		
			B =X7R	by no. of zeros.	M=±20%	by no. of zeros.		
			F=Y5V	And R is in	Z =-20/+80%	And R is in		
				place of		place of decimal		
				decimal point.		point.		
				eg.:		eg.:		
				103=10x10 ³		100 =10 VDC		
				=10,000pF		160 =16 VDC		
				=10nF		250 =25 VDC		
						500 =50 VDC		



5. EXTERNAL DIMENSIONS



Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbol		S (mm)	BW (mm)	P (mm)
0508 (1220)	2.00±0.15	1.25±0.15	0.85±0.10	Т	0.20±0.10	0.25±0.10	0.50±0.10
0612 (1632)	3.20±0.15	1.60±0.15	0.80±0.10	В	0.30±0.20	0.40±0.15	0.80±0.15

Reflow soldering process only.

6. GENERAL ELECTRICAL DATA

Dielectric	NI	P0	X7	Y5V		
Size	4x0402	4x0603	4x0402	4x0603	4x0603	
Capacitance*	10pF to 270pF	10pF to 470pF	1000pF to 100nF	180pF to 100nF	10nF to 100nF	
Capacitance tolerance**	J (±5%), K (±10%)		K (±10%),	K (±10%), M (±20%)		
Rated voltage (WVDC)	50V	25, 50V	10V, 16V, 25V, 50V	16V, 25V, 50V	16V, 50V	
Q/Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		Ur=50V Ur=25V&1 Ur=10V	Ur=50V, ≤5% Ur=16V, ≤7%		
Insulation resistance at Ur	≥10	GΩ	≥10GΩ or RxC≥500ΩxF whichever is less			
Operating temperature		-55 to	+125℃	-25 to +85℃		
Capacitance characteristic	±30	opm	±15	+30/-80%		
Termination		Ni/Sn (lead-free termination)				

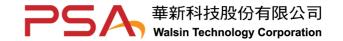
^{*} Measured at 30~70% related humidity.

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% at the conditions of 25℃ ambient temperature.

X7R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 25℃ ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 20℃ ambient temperature.

^{**} Preconditioning for Class II MLCC: Perform a heat treatment at 150±10℃ for 1 hour, then leave in a mbient condition for 24±2 hours before measurement.



7. CAPACITANCE RANGE

	SIZE 4 x 0402		4 x 0603										
	DIELECTRIC		X7R		N	NP0		X7R	X7R		Y5V		
R/	RATED VOLTAGE (VDC)		10	16	25	50	25	50	16	25	50	16	50
	10pF (100)	Т					В	В					
	15pF (150)	Т					В	В					
	22pF (220)	Т					В	В					
	33pF (330)	Т					В	В					
	47pF (470)	Т					В	В					
	68pF (680)	Т					В	В					
	100pF (101)	Т					В	В					
	150pF (151)	Т					В	В					
	180pF (181)	Т					В	В		В	В		
	220pF (221)	Т					В	В		В	В		
	270pF (271)	Т					В	В		В	В		
ø	330pF (331)						В	В		В	В		
Capacitance	470pF (471)						В	В		В	В		
acit	6,80pF (681)									В	В		
ар	1,000pF (102)		Т	Т	Т	Т				В	В		
0	1,500pF (152)		Т	Т	Т	Т				В	В		
	2,200pF (222)		Т	Т	Т	Т				В	В		
	3,300pF (332)		Т	Т	Т	Т				В	В		
	4,700pF (472)		Т	Т	Т	Т				В	В		
	6,800pF (682)		Т	Т	Т	Т				В	В		
	0.010µF (103)		Т	Т	Т	Т				В	В		В
	0.015µF (153)		Т	Т	Т				В	В	В		В
	0.022µF (223)		Т	Т	Т				В	В	В		В
	0.033µF (333)		Т	Т	Т				В				В
	0.047µF (473)		Т	Т	Т				В				В
	0.068µF (683)		Т	Т	Т				В				В
	0.10μF (104)		Т	Т	Т				В			В	В

^{1.} The letter in cell is expressed the symbol of product thickness.

8. PACKAGING DIMENSION AND QUANTITY

Size	Thickness/Syr	nbol	Paper tape		
Size	(mm)		7" reel	13" reel	
4 x 0402	0.85±0.10	Т	4k	-	
4 x 0603	0.80±0.10	В	4k	-	

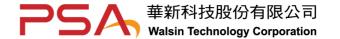
Unit: pieces



9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

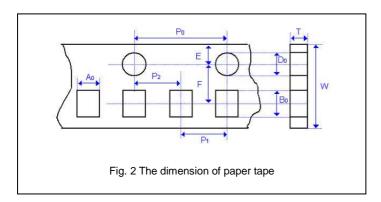
No.	Item		Test Condition		Requirements		
1.	Visual and				* No remark	able defect.	
	Mechanical				* Dimensions to conform to individual specification sheet.		
2.	Capacitance	Class I: (NP0)			* Shall not exceed the limits given in the detailed spec.		
3.	Q/ D.F.	1.0±0.2Vrms, 1	MHz±10%		NP0: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C		
	(Dissipation	Class II: (X7R, Y5V)			X7R: Ur=5	50V, ≤2.5%; Ur=25V&16V, ≤3.5%; Ur=10V, ≤5.0%	
	Factor)	1.0±0.2Vrms, 1	kHz±10%		Y5V: Ur=	50V, ≤5%; Ur=16V, ≤7%	
4.	Dielectric	* To apply 250% rated voltage.			* No evidend	ce of damage or flash over during test.	
	Strength	* Duration: 1 to	5 sec.				
		* Charge and d	lischarge current less than 50m/	٩.			
5.	Insulation	To apply rated	voltage for max. 120 sec.		≥10GΩ or R	xC≥500Ω-F whichever is smaller.	
	Resistance						
6.	Temperature	With no electric	cal load.	•			
	Coefficient	<u> </u>	Operating Temp		T.C.	Capacitance Change	
		<u> </u>	55~125℃ at 25℃		NP0	Within ±30ppm/°C	
		# + + + + + + + + + + + + + + + + + + +	55~125℃ at 25℃ 25~85℃ at 20℃		X7R Y5V	Within ±15% Within +30%/-80%	
		[13V]-	25~05 C at 20 C		130	WILIIII +3070/-0070	
7.	Adhesive	* Pressurizing force :		* No remark	able damage or removal of the terminations.		
	Strength of	5N (≤0603) a	and 10N (>0603)				
	Termination	* Test time: 10±	±1 sec.				
8.	Vibration	* Vibration freq	uency: 10~55 Hz/min.		* No remarkable damage.		
	Resistance	* Total amplitud	de: 1.5mm		* Cap change and Q/D.F.: To meet initial spec.		
			rs. (Two hrs each in three mutua	ally			
		perpendicular o	•				
		:	t to be made after keeping at roo	om temp. for			
_		24±2 hrs.					
9.	Solderability		rature: 235±5℃		95% min. cc	overage of all metalized area.	
40		* Dipping time:					
10.	Bending Test		art of substrate shall be pressuri	-	- I		
		1	zing rod at a rate of about 1 mm pecomes 1 mm and then the pre	•			
		maintained for		SSUIE SHAII DE			
			t to be made after keeping at roo	om temp for	X7R: within ±12.5% Y5V: within ±30%		
		24±2 hrs.	t to be made after Reeping at roc	om temp. for			
					(This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before		
					the test.)		
11.	Resistance to	* Solder temperature: 260±5℃			* No remarkable damage.		
		t * Dipping time: 10±1 sec			* Cap chang		
	_	1 11 1	20 to 150℃ for 1 minute before	imme rse the	NP0: withi	n ±2.5% or ±0.25pF whichever is larger.	
		capacitor in a e	eutectic solder.		X7R: withi	n ±7.5%	
		* Before initial i	measurement (Class II only): Pe	erform	Y5V: withii	n ±20%	
		150+0/-10℃ fo	r 1 hr and then set for 24±2 hrs	at room temp.	* Q/D.F., I.R	. and dielectric strength: To meet initial requirements.	
		* Measurement	t to be made after keeping at roo	om temp. for	* 25% max.	leaching on each edge.	
		24±2 hrs.					

No.	Item	Test Condition	Requirements		
12.	Temperature Cycle	* Conduct the five cycles according to the temperatures and time. Step Temp. (°C) Time (min.) 1 Min. operating temp. +0/-3 30±3 2 Room temp. 2~3 3 Max. operating temp. +3/-0 30±3 4 Room temp. 2~3 * Before initial measurement (Class II only): Perform 150+0/-10 °C for 1 hr and then set for 24±2 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change: NP0: within ±2.5% or ±0.25pF whichever is larger. X7R: within ±7.5% Y5V: within ±20% * Q/D.F., I.R. and dielectric strength: To meet initial requirements.		
13.	Humidity (Damp Heat) Steady State	* Test temp.: 40±2°C * Humidity: 90~95% RH * Test time: 500+24/-0hrs. *Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 24±2 hrs at r oom temp. * Measurement to be made after keeping at room temp. for 24±2 hrs	* No remarkable damage. * Cap change: NP0: within ±5.0% or ±0.5pF whichever is larger. X7R: within ±12.5% Y5V: within ±30% * Q/D.F. value: NP0: Cap≥30pF, Q≥350; 10pF≤Cap<30pF, Q≥275+2.5C Cap<10pF; Q≥200+10C X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5% Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10% * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		
14.	Humidity (Damp Heat) Load	* Test temp.: 40±2°C * Humidity: 90~95%RH * Test time: 500+24/-0 hrs. * To apply voltage: rated voltage. * Before initial measurement (Class II only): To apply test voltage for 1hr at 40°C and then set for 24±2 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change: NP0: within ±7.5% or ±0.75pF whichever is larger. X7R: within ±12.5% Y5V: within ±30% * Q/D.F. value: NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5% Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10% * I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.		
15.	High Temperature Load (Endurance)	* Test temp.: NP0, X7R: 125±3°C Y5V: 85±3°C * To apply voltage: 200% of rated voltage. * Test time: 1000+24/-0 hrs. *Before initial measurement (Class II only): To apply test voltage for 1hr at test temp. and then set for 24±2 hrs at room temp. *Measurement to be made after keeping at room temp. for 24±2 hrs	* No remarkable damage. * Cap change: NP0: within ±3.0% or ±0.3pF whichever is larger. X7R: within ±12.5% Y5V: within ±30% * Q/D.F. value: NP0: Cap≥30pF, Q≥350 10pF≤Cap<30pF, Q≥275+2.5C Cap<10pF, Q≥200+10C X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5% Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10% * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		

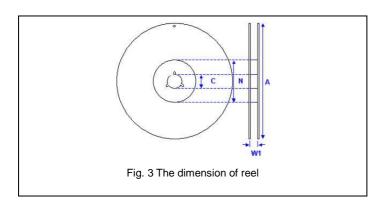


APPENDIXES

■ Tape & reel dimensions

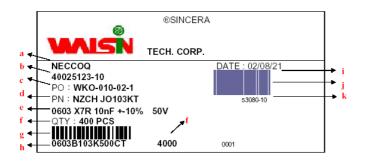


Size	4x0402	4x0603
Thickness	T	В
A_0	1.50±0.10	2.00±0.10
B ₀	2.30±0.10	3.50±0.10
Т	0.95±0.05	0.95±0.05
K ₀	-	-
W	8.00±0.10	8.00±0.10
P ₀	4.00±0.10	4.00±0.10
10xP ₀	40.0±0.10	40.0±0.10
P ₁	4.00±0.10	4.00±0.10
P ₂	2.00±0.05	2.00±0.05
D_0	1.55±0.05	1.50±0.05
D ₁	-	=
E	1.75±0.05	1.75±0.10
F	3.50±0.05	3.50±0.05



Size	4x0402, 4x0603
Reel size	7"
С	13.0+0.5/-0.2
W ₁	8.4+1.5/-0
Α	178.0±0.10
N	60.0+1/-0

■ Description of customer label

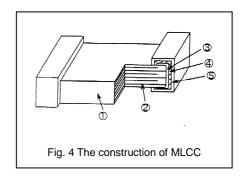


- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label



Constructions

No.	Nam	пе	NP0, X7R, Y5V
1	Ceramic r	material	BaTiO₃ based
2	Inner ele	ctrode	Ni
3		Inner layer	Cu
4	Termination	Middle layer	Ni
(5)		Outer layer	Sn (Matt)



Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N_2 within oven are recommended.

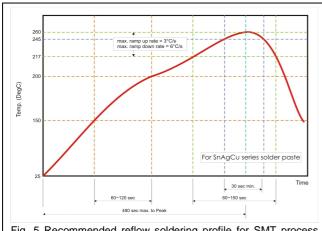


Fig. 5 Recommended reflow soldering profile for SMT process with SnAgCu series solder paste.



Fig. 6 Recommended wave soldering profile for SMT process with SnAgCu series solder.